## NSN 5961-01-295-8531

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View Online at https://aerobasegroup.com/nsn/5961-01-295-8531 **Inclosure Material:** Metal **Overall Length:** 1.330 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-210ac **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case and electrostatic sensitive **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 drain to source voltage and 200.0 drain to gate voltage **Current Rating Per Characteristic:** 30.00 amperes drain current **Power Rating Per Characteristic:** 150.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No

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